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GaAs INTEGRATED CIRCUIT $\mu PG2179TB$

L, S-BAND MEDIUM POWER SPDT SWITCH

DESCRIPTION

The μPG2179TB is a GaAs MMIC L, S-band SPDT (Single Pole Double Throw) switch for mobile phone and other L, S-band applications. This device operates with dual control voltages of 2.5 to 5.3 V. This device can operate from 0.05 to 3.0 GHz, with low insertion loss and high isolation.

This device is housed in a 6-pin super minimold package, and is suitable for high-density surface mounting.

★ FEATURES

*

 Switch control voltage 	: V _{cont (H)} = 2.5 to 5.3 V (3.0 V TYP.)
	: $V_{\text{cont (L)}} = -0.2 \text{ to } +0.2 \text{ V} (0 \text{ V TYP.})$
 Low insertion loss 	: Lins1 = 0.25 dB TYP. @ f = 0.05 to 1.0 GHz, Vcont (H) = 3.0 V, Vcont (L) = 0 V
	: Lins2 = 0.30 dB TYP. @ f = 1.0 to 2.0 GHz, Vcont (H) = 3.0 V, Vcont (L) = 0 V
	: Lins3 = 0.35 dB TYP. @ f = 2.0 to 2.5 GHz, Vcont (H) = 3.0 V, Vcont (L) = 0 V
	: Lins4 = 0.40 dB TYP. @ f = 2.5 to 3.0 GHz, Vcont (H) = 3.0 V, Vcont (L) = 0 V
 High isolation 	: ISL1 = 27 dB TYP. @ f = 0.05 to 2.0 GHz, Vcont (H) = 3.0 V, Vcont (L) = 0 V
	: ISL2 = 24 dB TYP. @ f = 2.0 to 3.0 GHz, Vcont (H) = 3.0 V, Vcont (L) = 0 V
 Power handling 	: Pin (0.1 dB) = +29.0 dBm TYP. @ f = 0.5 to 3.0 GHz, Vcont (H) = 3.0 V, Vcont (L) = 0 V
	: Pin (1 dB) = +32.0 dBm TYP. @ f = 0.5 to 3.0 GHz, Vcont (H) = 3.0 V, Vcont (L) = 0 V

+ High-density surface mounting : 6-pin super minimold package ($2.0 \times 1.25 \times 0.9$ mm)

APPLICATIONS

- · L, S-band digital cellular or cordless telephone
- PCS, W-LAN, WLL and Bluetooth[™] etc.

★ ORDERING INFORMATION

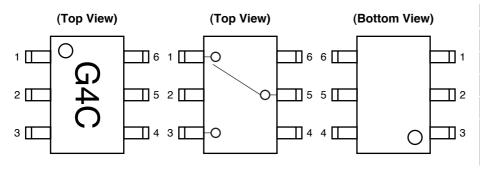
Part Number	Package	Marking	Supplying Form
<i>µ</i> РG2179TB-E4-A	6-pin super minimold	G4C	 Embossed tape 8 mm wide Pin 4, 5, 6 face the perforation side of the tape Qty 3 kpcs/reel

Remark To order evaluation samples, contact your nearby sales office. Part number for sample order: *µ*PG2179TB-A

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



Dia Ma	Dia Mara
Pin No.	Pin Name
1	OUTPUT1
2	GND
3	OUTPUT2
4	Vcont2
5	INPUT
6	Vcont1

TRUTH TABLE

Vcont1	Vcont2	INPUT-OUTPUT1	INPUT-OUTPUT2
Low	High	ON	OFF
High	Low	OFF	ON

ABSOLUTE MAXIMUM RATINGS (TA = +25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Switch Control Voltage	Vcont	6.0 Note	V
Input Power	Pin	+33	dBm
Operating Ambient Temperature	TA	–45 to +85	°C
Storage Temperature	Tstg	–55 to +150	°C

***** Note $|V_{cont1} - V_{cont2}| \le 6.0 V$

RECOMMENDED OPERATING RANGE (TA = +25°C, unless otherwise specified)

	Parameter	Symbol	MIN.	TYP.	MAX.	Unit
*	Switch Control Voltage (H)	Vcont (H)	2.5	3.0	5.3	V
	Switch Control Voltage (L)	Vcont (L)	-0.2	0	0.2	V

★ ELECTRICAL CHARACTERISTICS

(TA = +25°C, V_{cont (H)} = 3.0 V, V_{cont (L)} = 0 V, DC blocking capacitors = 100 pF, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss 1	Lins1	f = 0.05 to 1.0 GHz ^{Note1}	-	0.25	0.45	dB
Insertion Loss 2	Lins2	f = 1.0 to 2.0 GHz	-	0.30	0.50	dB
Insertion Loss 3	Lins3	f = 2.0 to 2.5 GHz	-	0.35	0.55	dB
Insertion Loss 4	Lins4	f = 2.5 to 3.0 GHz	-	0.40	0.60	dB
Isolation 1	ISL1	f = 0.05 to 2.0 GHz ^{Note1}	23	27	-	dB
Isolation 2	ISL2	f = 2.0 to 3.0 GHz	20	24	-	dB
Input Return Loss	RLin	f = 0.05 to 3.0 GHz ^{Note1}	15	20	-	dB
Output Return Loss	RLout	f = 0.05 to 3.0 GHz ^{Note1}	15	20	-	dB
0.1 dB Loss Compression	Pin (0.1 dB)	f = 2.0 GHz	+25.5	+29.0	-	dBm
Input Power ^{Note2}		f = 2.5 GHz	+25.5	+29.0	-	dBm
		f = 0.5 to 3.0 GHz	-	+29.0	-	dBm
Switch Control Current	Icont	No signal	-	4	20	μA
Switch Control Speed	tsw	50%CTL to 90/10%RF	-	50	500	ns

Note1. DC blocking capacitor = 1 000 pF at f = 0.05 to 0.5 GHz.

2. Pin (0.1 dB) is the measured input power level when the insertion loss increases 0.1 dB more than that of linear range.

***** STANDARD CHARACTERISTICS FOR REFERENCE

(TA = +25°C, V_{cont} (H) = 3.0 V, V_{cont} (L) = 0 V, DC blocking capacitors = 100 pF, unless otherwise specified)

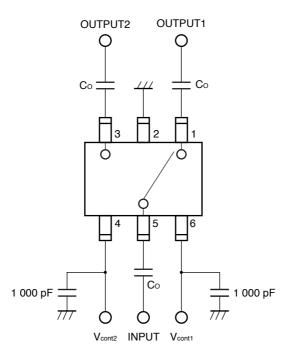
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
1 dB Loss Compression	Pin (1 dB)	f = 0.5 to 3.0 GHz	-	+32.0	-	dBm
Input Power ^{™ote}						
3rd Order Intermodulation Intercept	IIP₃	f = 0.5 to 3.0 GHz, 2 tone,	-	+60.0	-	dBm
Point		5 MHz spicing				

Note Pin (1 dB) is the measured input power level when the insertion loss increases 1 dB more than that of linear range.

★ Caution When using this IC, a DC coupling capacitor must be externally attached to the I/O pins.

A DC coupling capacitor with a capacitance of 100 pF or lower is recommended when using a frequency of 0.5 GHz or higher, and one with a capacitance of 1,000 pF is recommended when using a frequency of less than 0.5 GHz. The ideal value changes depending on the frequency and bandwidth used, so select a capacitor with a suitable capacitance according to the usage conditions.

★ EVALUATION CIRCUIT



Remark Co : 0.05 to 0.5 GHz 1 000 pF 0.5 to 3.0 GHz 100 pF

The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

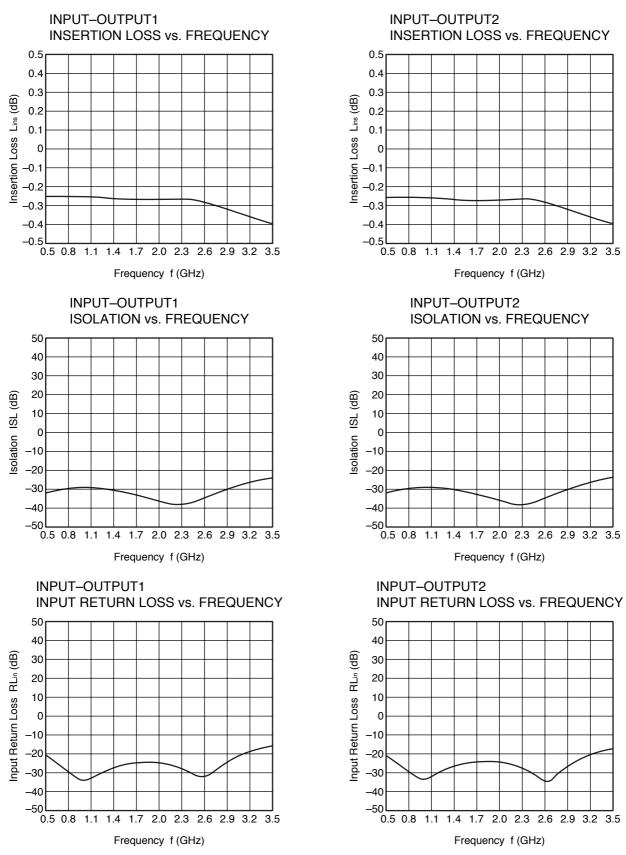
- Vcont2 6pin SMM SPDT SW 0 0 Vc2 0 0 0 OUTPUT2 OUT 2 0 0 0 ° C2 С 0 0 C1 0 0 0 0 G4C INPUT 0 C3 C1 0 0 ° C1 IN 0 0 0 0 0 0 0 OUT 1 OUTPUT1 0 0 0 Vc1 0 0 0 Vcont1
- ★ ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD

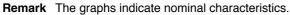
USING THE NEC EVALUATION BOARD

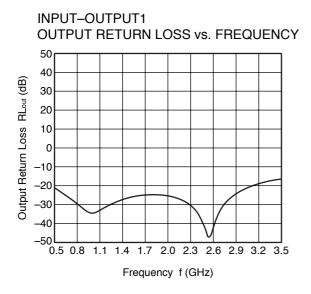
Symbol	Values
C1, C2, C3	100 pF
C4, C5	1 000 pF

TYPICAL CHARACTERISTICS

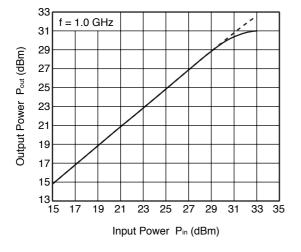
★ (TA = +25°C, Vcont (H) = 3.0 V, Vcont (L) = 0 V, DC blocking capacitors = 100 pF, unless otherwise specified)





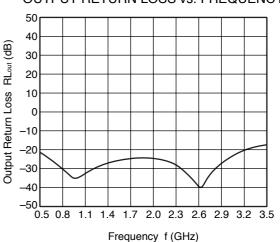


OUTPUT POWER vs. INPUT POWER

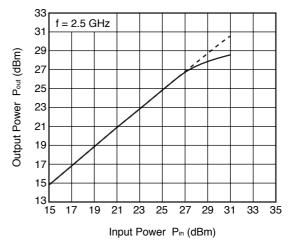


Remark The graphs indicate nominal characteristics.

INPUT-OUTPUT2 OUTPUT RETURN LOSS vs. FREQUENCY

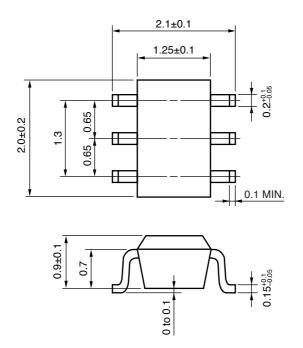


OUTPUT POWER vs. INPUT POWER



PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) Time at peak temperature Time at temperature of 220°C or higher Preheating time at 120 to 180°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 60 seconds or less : 120±30 seconds : 3 times : 0.2%(Wt.) or below	IR260
VPS	Peak temperature (package surface temperature) Time at temperature of 200°C or higher Preheating time at 120 to 150°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass)	: 215°C or below : 25 to 40 seconds : 30 to 60 seconds : 3 times : 0.2%(Wt.) or below	VP215
Wave Soldering	Peak temperature (molten solder temperature) Time at peak temperature Preheating temperature (package surface temperature) Maximum number of flow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 120°C or below : 1 time : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (pin temperature) Soldering time (per side of device) Maximum chlorine content of rosin flux (% mass)	: 350°C or below : 3 seconds or less : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

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- "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

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M8E 00.4-0110

Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	 Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
	Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	Do not lick the product or in any way allow it to enter the mouth.

▶ For further information, please contact

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